2SK1637, 2SK2422

Silicon N-Channel MOS FET

HITACHI

Application

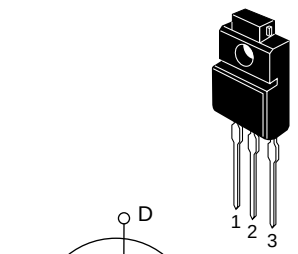
High speed power switching

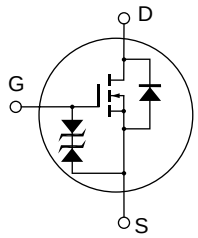
Features

- Low on-resistance
- High speed switching
- Low drive current
- No secondary breakdown
- Suitable for switching regulator and DC-DC converter

Outline

TO-220FM





1. Gate
2. Drain
3. Source

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Absolute Maximum Ratings (Ta = 25°C)

Item		Symbol	Ratings	Unit
Drain to source voltage	2SK1637	V_{DSS}	600	V
	2SK2422		650	
Gate to source voltage		V_{GSS}	±30	V
Drain current		I_D	4	A
Drain peak current		$I_{D(pulse)}$*[1]	16	A
Body to drain diode reverse drain current		I_{DR}	4	A
Channel dissipation		Pch*[2]	35	W
Channel temperature		Tch	150	°C
Storage temperature		Tstg	–55 to +150	°C

Note 1. PW 10 µs, duty cycle 1%
2. Value at T_C = 25°C

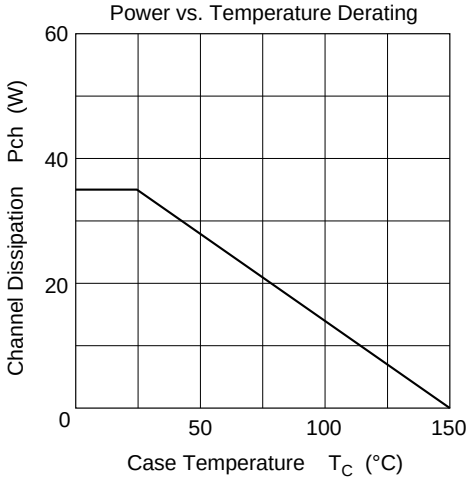
Electrical Characteristics (Ta = 25°C)

Item		Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	2SK1637	$V_{(BR)DSS}$	600	—	—	V	I_D = 10 mA, V_{GS} = 0
	2SK2422		650				
Gate to source breakdown voltage		$V_{(BR)GSS}$	±30	—	—	V	I_G = ±100 µA, V_{DS} = 0
Gate to source leak current		I_{GSS}	—	—	±10	µA	V_{GS} = ±25 V, V_{DS} = 0
Zero gate voltage drain current	2SK1637	I_{DSS}	—	—	250	µA	V_{DS} = 500 V, V_{GS} = 0
	2SK2422						V_{DS} = 550 V, V_{GS} = 0
Gate to source cutoff voltage		$V_{GS(off)}$	2.0	—	3.0	V	I_D = 1 mA, V_{DS} = 10 V
Static Drain to source on state resistance	2SK1637	$R_{DS(on)}$	—	1.8	2.4		I_D = 2 A, V_{GS} = 10 V *[1]
	2SK2422		—	2.0	2.6		
Forward transfer admittance		|yfs|	2.2	3.5	—	S	I_D = 2 A, V_{DS} = 10 V *[1]
Input capacitance		Ciss	—	600	—	pF	V_{DS} = 10 V, V_{GS} = 0, f = 1 MHz
Output capacitance		Coss	—	140	—	pF	
Reverse transfer capacitance		Crss	—	25	—	pF	
Turn-on delay time		$t_{d(on)}$	—	8	—	ns	I_D = 2 A, V_{GS} = 10 V, R_L = 15
Rise time		t_r	—	30	—	ns	
Turn-off delay time		$t_{d(off)}$	—	60	—	ns	
Fall time		t_f	—	35	—	ns	
Body to drain diode forward voltage		V_{DF}	—	0.9	—	V	I_F = 4 A, V_{GS} = 0
Body to drain diode reverse recovery time		t_{rr}	—	300	—	ns	I_F = 4 A, V_{GS} = 0, di_F/dt = 100 A/µs

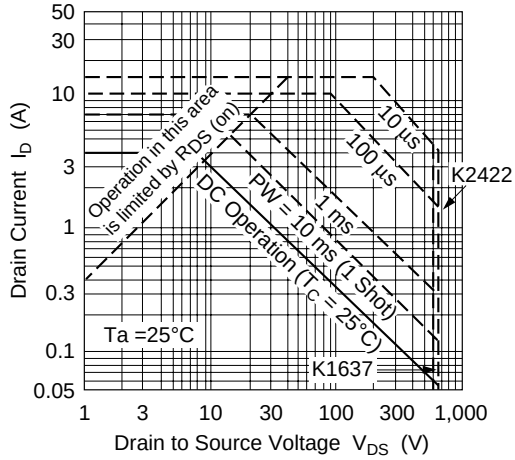
Note 1. Pulse test

See characteristics curves of 2SK1402, 2SK1402A.

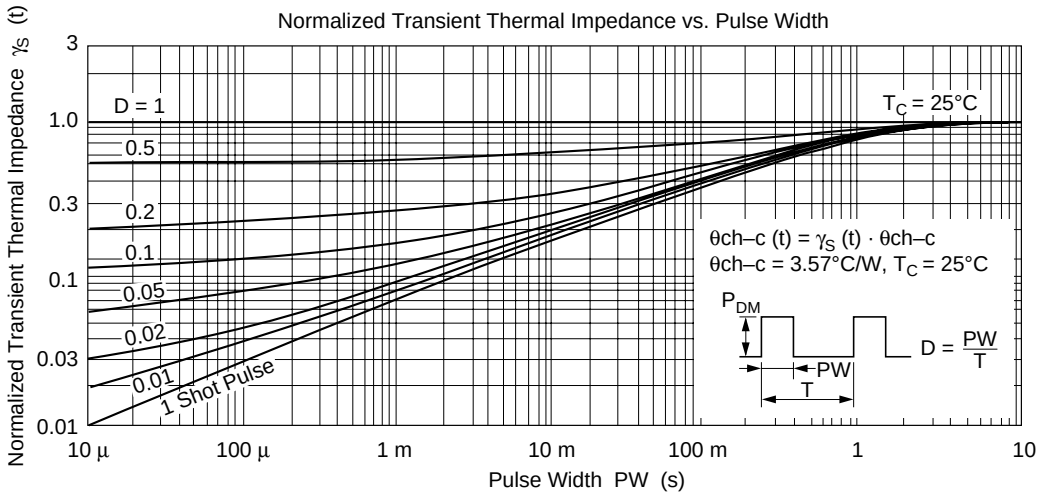
Power vs. Temperature Derating



Maximum Safe Operation Area



Normalized Transient Thermal Impedance vs. Pulse Width



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HITACHI

Hitachi, Ltd.
Semiconductor & IC Div.
Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100, Japan
Tel: Tokyo (03) 3270-2111
Fax: (03) 3270-5109

For further information write to:

Hitachi America, Ltd.
Semiconductor & IC Div.
2000 Sierra Point Parkway
Brisbane, CA. 94005-1835
U S A
Tel: 415-589-8300
Fax: 415-583-4207

Hitachi Europe GmbH
Electronic Components Group
Continental Europe
Dornacher Straße 3
D-85622 Feldkirchen
München
Tel: 089-9 91 80-0
Fax: 089-9 29 30 00

Hitachi Europe Ltd.
Electronic Components Div.
Northern Europe Headquarters
Whitebrook Park
Lower Cookham Road
Maidenhead
Berkshire SL6 8YA
United Kingdom
Tel: 0628-585000
Fax: 0628-778322

Hitachi Asia Pte. Ltd.
16 Collyer Quay #20-00
Hitachi Tower
Singapore 0104
Tel: 535-2100
Fax: 535-1533

Hitachi Asia (Hong Kong) Ltd.
Unit 706, North Tower,
World Finance Centre,
Harbour City, Canton Road
Tsim Sha Tsui, Kowloon
Hong Kong
Tel: 27359218
Fax: 27306071